

MBR10L100CT

Low VF Isolated 10.0Amp Schottky Barrier Rectifier **TO-220AB**

ROHS COMPLIANCE



Features

- ♦ Low power loss, high efficiency
- ♦ High current capability, Low forward voltage drop.
- Plastic material used carries Underwriters ♦ Laboratory Classification 94V-0
- ♦ High surge current capabilitry
- ∻ Qualified as per AEC-Q101
- ♦ Guard-ring for transient protection
- ♦ For use in low voltage, high frequency inventor, freewheeling, and polarity protection application
- ∻ High temperature soldering guaranteed: 260°C/10S/.375"(9.5mm) lead lengths 5 lbs tension

Mechanical Data

- ♦ Case: TO-220AB
- ♦ Terminals: Pure tin plated leads, solderable per MIL-STD-202, Method 208 guaranteed
- ∻ Polarity: As marked
- ♦ Weight: 1.88 grams
- ♦ Mounting Torque:5 in-lbs. max.
- ♦ Mounting position:Any

Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%

.113(2.87) .103(2.82)	.412(10.5) MAX	OIA <u>.154(3.91)</u> <u>.148(3.74)</u> <u>.27(6.8</u> <u>.23(5.8</u>	<u>.185(4.70</u> .175(4.44	<u>.055(1.40)</u> .045(1.14)
.16(4.06) .14(3.56) .037(0.94) .027(0.68)	PIN1 2 3	.594(15.1) .579(14.7) .579(14.7) .56(14.22) .53(13.46)		(2.79) (2.54)
		05(267) 195(241) N 1 0→→ N 3 0→→	-0 CASE PIN 2	ţ

Dimensions in inches and (millimeters)

GYWW MBR10LXXXCT -

Marking Diagram

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MBR10LXXXCT = Specific Device Code G = Green Compound

- = Year Code
- = Work Week Code

Parameter		MBR10L100CT		Unit
Maximum Repetitive Peak Reverse Voltage	V _{RRM}	100		V
Maximum RMS Voltage		70		V
Maximum DC blocking voltage	V _{DC}	100		V
Maximum Average Forward Rectified Current	I _{F(AV)}	10		А
Peak Repetitive Forward Current (Rated VR, Square Wave, 20KHz)	I _{F(RMS)}	10		А
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load	I _{FSM}	120		А
Peak Repetitive Reverse Surge Current (Note 1)	I _{RRM}	1		А
Maximum Instantaneous Forward Voltage (Pulse test: tp=300us, δ < 1%) @ 5A / Ta=25℃ @ 5A / Ta=125℃ @ 10A / Ta=25℃ @ 10A / Ta=125℃	V _F	TYP. 0.73 0.59 0.82 0.66	Max. 0.76 0.65 0.85 0.71	v
Maximum Reverse Current (Pulse test: tp=300us, δ < 1%) Ta=25 $^\circ\!\mathbb{C}$ Ta=125 $^\circ\!\mathbb{C}$	I _R	TYP. 0.3 0.5	Max. 20 15	uA mA
Voltage rate of change (rated V_R)	dV/dt	10,000		V/uS
Typical Junction Capacitance (Note 2)	Cj	185		pF
Typical Thermal Resistance (Note 3)	$R_{ extsf{ heta}JC}$	2.8		^o C/W
Operating Temperature Range	TJ	-55 to + 150		O _O
Storage Temperature Range		-55 to + 150		OC

Note1: 2.0uS Pulse Width, F=1.0KHz, Continues 10 cycles

Note2: Measured at 1 MHz and Applied Reverse Voltage of 4.0 V D.C.

Note3: Mount on Heatsink Size of 4" x 6" x 0.25" Al-Plate



RATINGS AND CHARACTERISTIC CURVES (MBR10L100CT)



Fig. 5 Typical Junction Capacitance



Fig. 6 Typical Transient Thermal Impedance

